

# NCE N-Channel Enhancement Mode Power MOSFET

## Description

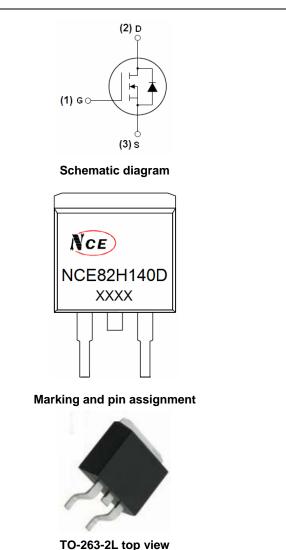
The NCE82H140D uses advanced trench technology and design to provide excellent  $R_{DS(ON)}$  with low gate charge. It can be used in a wide variety of applications.

#### **General Features**

- $V_{DS} = 82V, I_D = 140A$  $R_{DS(ON)} < 6m\Omega @ V_{GS} = 10V$  (Typ:4.3m $\Omega$ )
- Special process technology for high ESD capability
- High density cell design for ultra low Rdson
- Fully characterized avalanche voltage and current
- Good stability and uniformity with high E<sub>AS</sub>
- Excellent package for good heat dissipation

# Application

- Power switching application
- Hard switched and high frequency circuits
- Uninterruptible power supply



#### 100% UIS TESTED!

**100% ΔVds TESTED!** 

#### Package Marking and Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
NCE82H140D	NCE82H140D	TO-263-2L	-	-	-

# Absolute Maximum Ratings (T<sub>c</sub>=25<sup>°</sup>Cunless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	Vds	82	V
Gate-Source Voltage	Vgs	±20	V
Drain Current-Continuous	Ι <sub>D</sub>	140	А
Drain Current-Continuous(T <sub>C</sub> =100 ℃)	I <sub>D</sub> (100℃)	99	А
Pulsed Drain Current	I <sub>DM</sub>	480	А
Maximum Power Dissipation	PD	220	W
Derating factor		1.47	W/℃
Single pulse avalanche energy (Note 5)	E <sub>AS</sub>	1200	mJ
Operating Junction and Storage Temperature Range	T <sub>J</sub> ,T <sub>STG</sub>	-55 To 175	°C



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# NCE82H140D

#### **Thermal Characteristic**

Thermal Resistance, Junction-to-Case (Note 2)	R <sub>θJc</sub>	0.68	°C/W
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# **Electrical Characteristics (T<sub>C</sub>=25**<sup>°</sup>C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics	·					
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V I <sub>D</sub> =250µA	82	-	-	V
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =82V,V <sub>GS</sub> =0V	-	-	1	μA
Gate-Body Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> =±20V,V <sub>DS</sub> =0V	-	-	±100	nA
On Characteristics (Note 3)						
Gate Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS}=V_{GS}$ , $I_{D}=250\mu A$	2	3	4	V
Drain-Source On-State Resistance	R <sub>DS(ON)</sub>	$V_{GS}$ =10V, I <sub>D</sub> =20A	-	4.3	6.0	mΩ
Forward Transconductance	<b>g</b> fs	V <sub>DS</sub> =5V,I <sub>D</sub> =20A	65	-	-	S
Dynamic Characteristics (Note4)						
Input Capacitance	C <sub>lss</sub>		-	7900	-	PF
Output Capacitance	C <sub>oss</sub>	$V_{DS}$ =40V, $V_{GS}$ =0V,	-	445	-	PF
Reverse Transfer Capacitance	C <sub>rss</sub>	F=1.0MHz	-	384	-	PF
Switching Characteristics (Note 4)	<b>I</b> I					<u></u>
Turn-on Delay Time	t <sub>d(on)</sub>		-	23	-	nS
Turn-on Rise Time	tr	$V_{DD}$ =30V, R <sub>L</sub> =1 $\Omega$	-	42	-	nS
Turn-Off Delay Time	t <sub>d(off)</sub>	$V_{GS}$ =10V, $R_{GEN}$ =2.5 $\Omega$	-	75	-	nS
Turn-Off Fall Time	t <sub>f</sub>		-	26	-	nS
Total Gate Charge	Qg		-	158	-	nC
Gate-Source Charge	Q <sub>gs</sub>	$V_{DS}$ =40V,I <sub>D</sub> =20A,	-	32	-	nC
Gate-Drain Charge	Q <sub>gd</sub>	V <sub>GS</sub> =10V	-	51	-	nC
Drain-Source Diode Characteristics	. I					
Diode Forward Voltage (Note 3)	V <sub>SD</sub>	V <sub>GS</sub> =0V,I <sub>S</sub> =140A	-	-	1.2	V
Diode Forward Current (Note 2)	I <sub>S</sub>	-	_	-	140	A
Reverse Recovery Time	t <sub>rr</sub>	TJ = 25°C, IF = 20A	_	50	-	nS
Reverse Recovery Charge	Qrr	di/dt = 100A/µs <sup>(Note3)</sup>	-	110	-	nC

#### Notes:

1. Repetitive Rating: Pulse width limited by maximum junction temperature.

2. Surface Mounted on FR4 Board, t  $\leq$  10 sec.

3. Pulse Test: Pulse Width ≤ 300 $\mu$ s, Duty Cycle ≤ 2%.

4. Guaranteed by design, not subject to production

5. EAS condition: Tj=25  $^\circ\!\mathrm{C}$  ,VDD=40V,VG=10V,L=0.5mH,Rg=25 $\Omega$ 



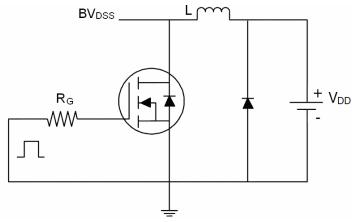
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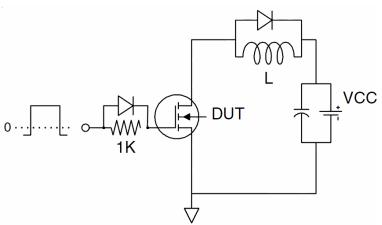


# Test circuit

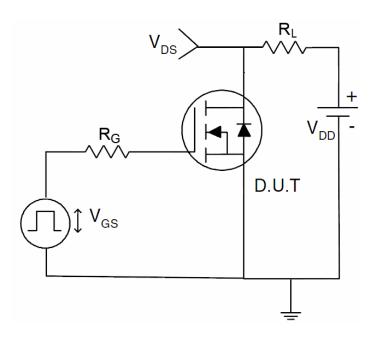
1) E<sub>AS</sub> test Circuit



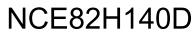
# 2) Gate charge test Circuit



## 3) Switch Time Test Circuit





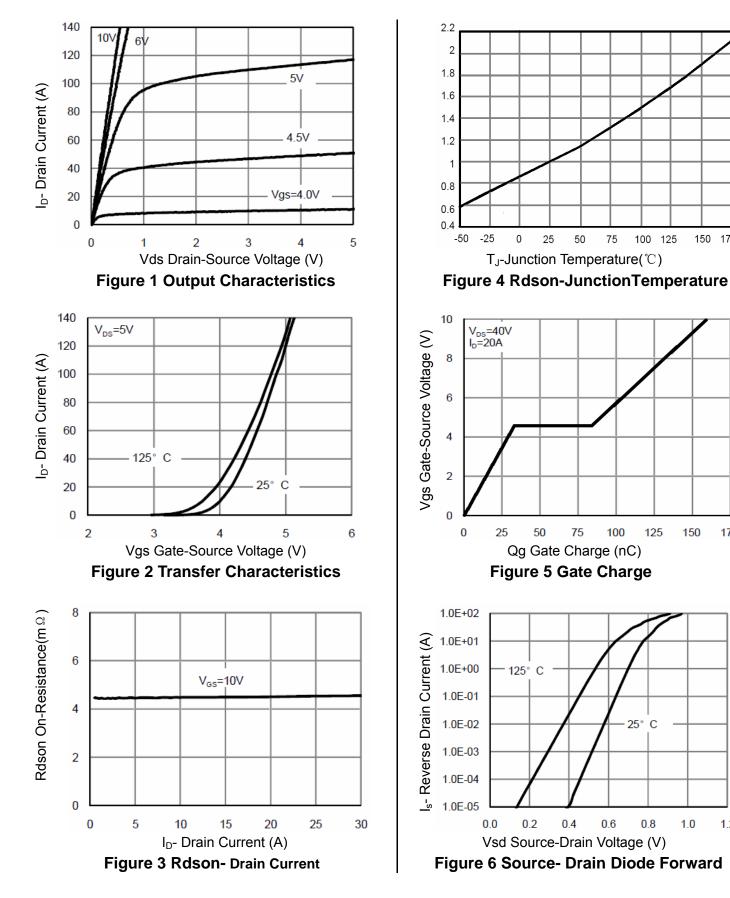


150 175

150

175

# **Typical Electrical and Thermal Characteristics (Curves)**



1.2

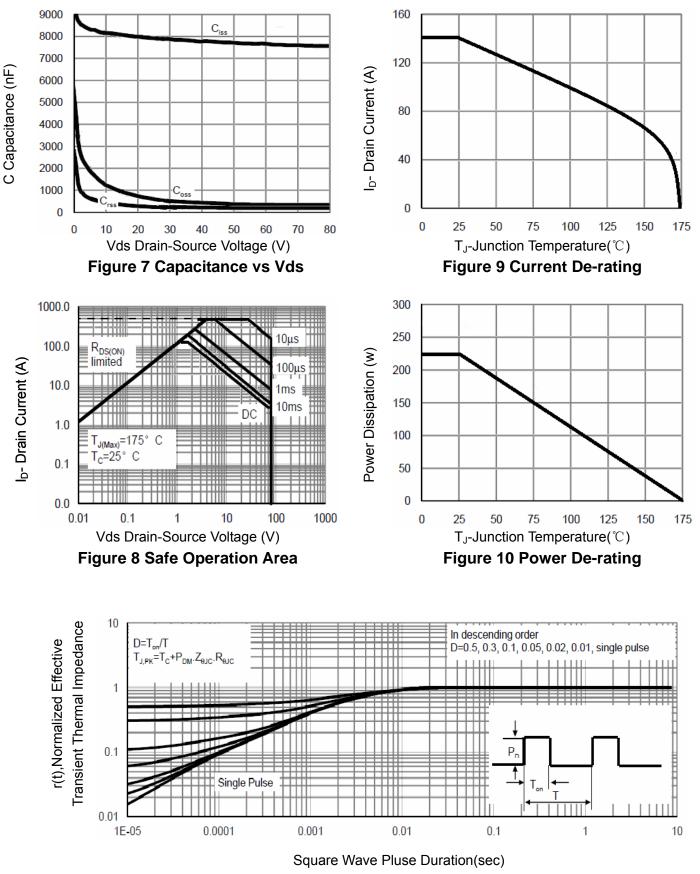
1.0



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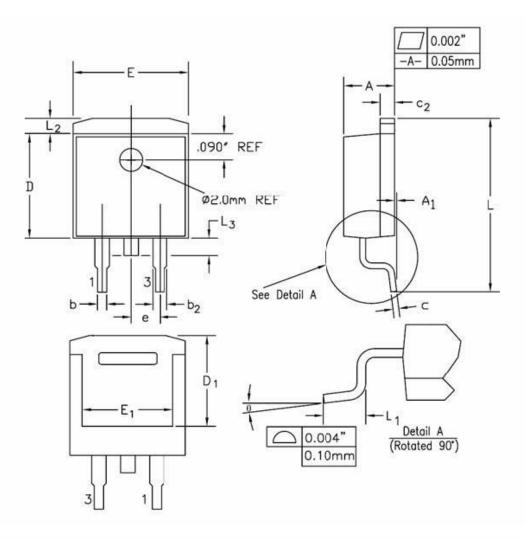


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# **TO-263-2L Package Information**



SYMBOL	INCHES		MILLIM	NOTES	
STWDUL	MIN	MAX	MIN	MAX	NOTES
A	0.170	0.180	4.32	4.57	
A1	-	0.010	-	0.25	
b	0.028	0.037	0.71	0.94	
b2	0.045	0.055	1.15	1.40	
С	0.018	0.024	0.46	0.61	
c2	0.048	0.055	1.22	1.40	
D	0.350	0.370	8.89	9.40	
D1	0.315	0.324	8.01	8.23	
E	0.395	0.405	10.04	10.28	
E1	0.310	0.318	7.88	8.08	
e	0.100 BSC.		2.54 BSC.		
L	0.580	0.620	14.73	15.75	
L1	0.090	0.110	2.29	2.79	
L2	0.045	0.055	1.15	1.39	
L3	0.050	0.070	1.27	1.77	
θ	0°	8°	0°	8°	





NCE82H140D

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